

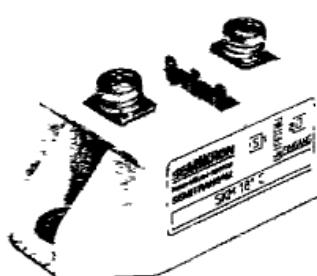
**Absolute Maximum and Minimum Ratings<sup>1)</sup>**

Symbol	Rating	Value min.	Value max.	Unit
V <sub>sup</sub>	Driver supply voltage	—	18	V
V <sub>j</sub>	Input signal voltage	-0,3	V <sub>sup</sub> + 0,3	V
V <sub>isol</sub>	Input-Output	—	2500	V-
T <sub>case</sub>	Case temperature <sup>2)</sup>	-40	+85	°C
T <sub>stg</sub>	Storage temperature	-40	+85	°C

**SEMITRANS® M**  
**Single Switch Power**  
**MOSFET Modules with**  
**Built-in Driver Circuit**

SKM 111 ARC<sup>3)</sup> SKM 181 C  
 SKM 121 ARC<sup>3)</sup> SKM 181 FC  
 SKM 141 C SKM 191 C  
 SKM 151 C SKM 191 FC  
 SKM 151 FC

T-39-15

**Operating Conditions**

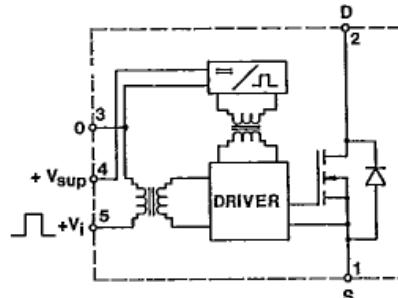
Symbol	Rating	Value min.	Value max.	Unit
V <sub>sup</sub>	Driver supply voltage	8	15	V
V <sub>IL</sub>	Logic 0 input voltage (LOW)	—	0,14 · V <sub>sup</sub>	V
V <sub>IH</sub>	Logic 1 input voltage (HIGH)	0,86 · V <sub>sup</sub>	—	V
f	Operating frequency	0	50 <sup>4)</sup>	kHz
t <sub>p</sub>	Input pulse duration	0,5 <sup>5)</sup>	—	μs
t <sub>p(off)</sub>	Input pulse off-time	0,5 <sup>5)</sup>	—	μs

**Electrical Characteristics @ T<sub>case</sub> = 25 °C**

Symbol	Rating	Value min.	Value max.	Unit
I <sub>sup</sub>	Driver supply current quiescent; V <sub>sup</sub> = 15 V	—	19	mA
I <sub>i</sub>	Input signal current	—	see Fig. 3	μA

Switching times (see Fig. 62)

Module	Rating	Test conditions			Typical switching times			
		V <sub>Ds</sub> V	V <sub>DD</sub> V	I <sub>b</sub> A	t <sub>d(on</sub> ns	t <sub>r</sub> ns	t <sub>d(off</sub> μs	t <sub>f</sub> ns
SKM 111 ARC	100	50	130	280	500	1,5	600	
SKM 121 ARC	200	100	80	280	220	1,8	450	
SKM 141 C	400	200	60	250	120	2	450	
SKM 151 C	500	250	36	250	120	2	450	
SKM 151 FC	500	250	36	350	160	2	400	
SKM 181 C	800	400	23	350	130	2,3	400	
SKM 181 FC	800	400	23	330	120	2,5	430	
SKM 191 C	1000	500	17	350	150	2,5	450	
SKM 191 FC	1000	500	18	350	150	2,5	450	

**Features**

- Internal isolation between input and output stages
- The power supply for the driver must not be isolated
- CMOS compatible input

**Typical Applications**

- DC choppers
- AC motor drives
- Power supplies for LASERS
- Uninterruptible power supplies
- Ultrasonic generator
- Plasma cutting
- Inductive heating
- Electronic welding

This is an electrostatic discharge sensitive device (ESDS). Please observe the international standard IEC 747-1, Chapter IX.

<sup>1)</sup> For the ratings and characteristics of the power MOSFET output stages see the corresponding tables and diagrams

<sup>2)</sup> The case temperature of the module is the ambient temperature of the built-in driver

<sup>3)</sup> These types contain gate resistors to reduce dI/dt

<sup>4)</sup> For higher operating frequencies please consult your SEMIKRON service office

<sup>5)</sup> Important! See also the technical explanations in Part A

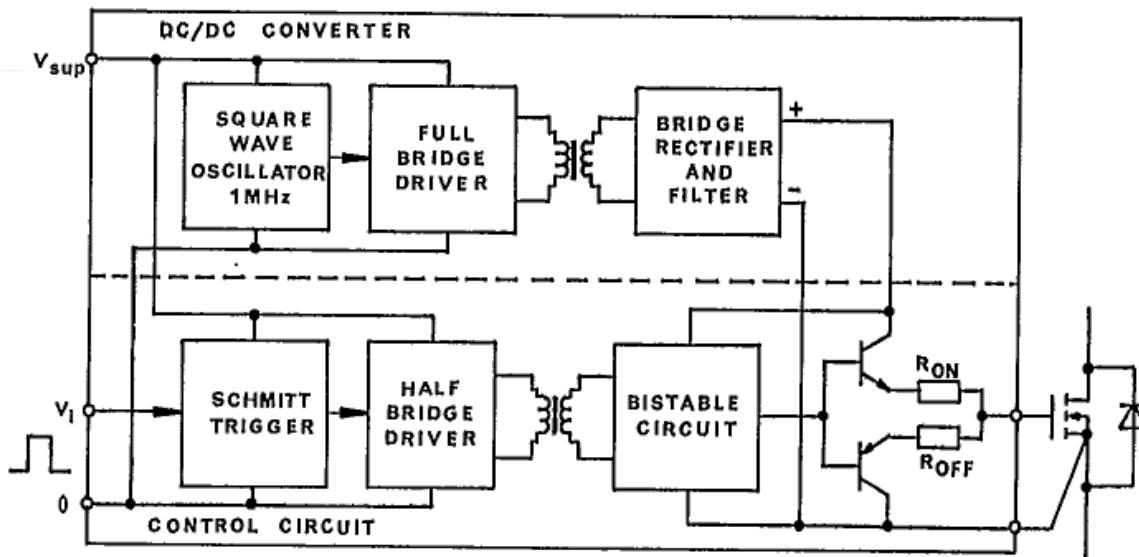


Fig. 61 Block diagram of the driver circuit

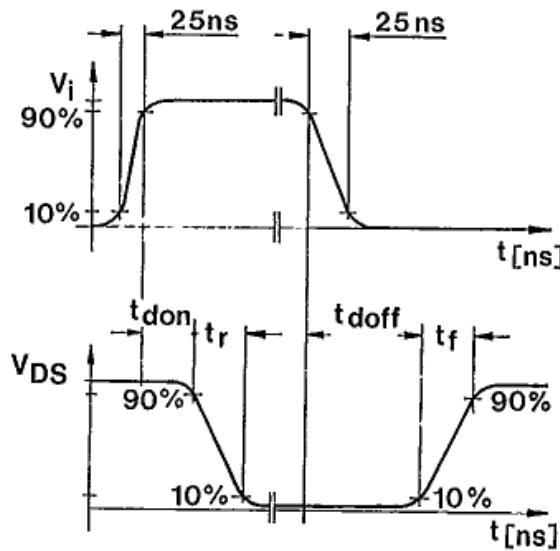


Fig. 62 Definitions of the switching times

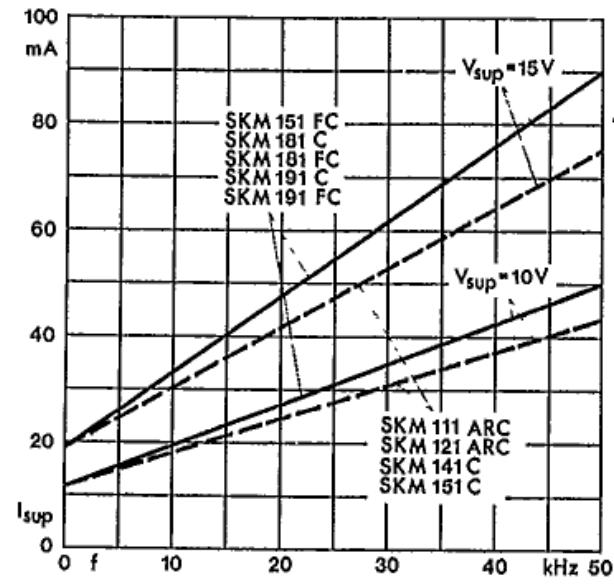


Fig. 63 Supply current vs. operating frequency

